

Low-voltage variable capacitance diode

FEATURES

- Ultra small plastic SMD package
- C4: 3 pF; ratio: 2.1
- Low series resistance.

APPLICATIONS

- Voltage controlled oscillators (VCO).

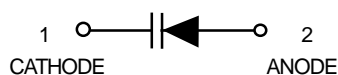
DESCRIPTION

The BB145 is a planar technology variable capacitance diode in a SOD523 (SC-79) package.

BB 145



SOD523 SC-79



MARKING CODE:U



LIMITING VALUES In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		–	6	V
V_{RM}	peak reverse voltage	in series with a 10 k Ω resistor	–	8	V
I_F	continuous forward current		–	20	mA
T_{stg}	storage temperature		–55	+150	°C
T_j	operating junction temperature		–55	+150	°C

ELECTRICAL CHARACTERISTICS $T_j=25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_R	reverse current	$V_R = 6\text{ V}$; see Fig.2	–	–	10	nA
		$V_R = 6\text{ V}$; $T_j = 85^\circ\text{C}$; see Fig.2	–	–	200	nA
r_s	diode series resistance	$f = 470\text{ MHz}$; $V_R = 1\text{ V}$	–	–	0.6	Ω
C_d	diode capacitance	$V_R = 1\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	6.4	–	7.4	pF
		$V_R = 4\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	2.75	–	3.25	pF
$\frac{C_{d(1V)}}{C_{d(4V)}}$	capacitance ratio	$f = 1\text{ MHz}$	2	–	–	

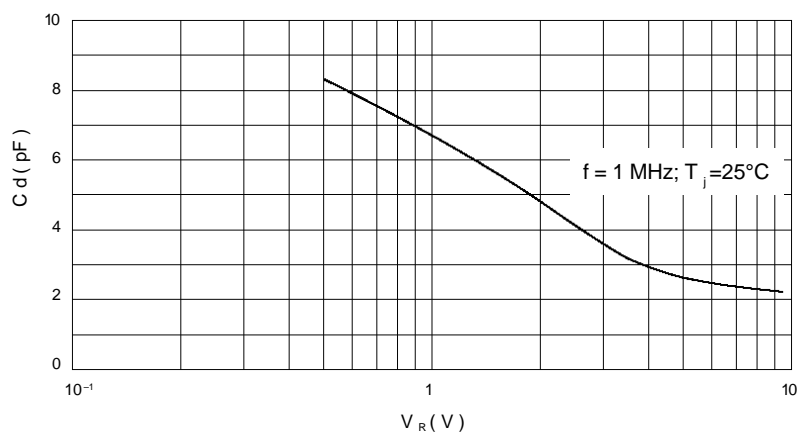
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Fig.1 Diode capacitance as a function of reverse voltage; typical values.

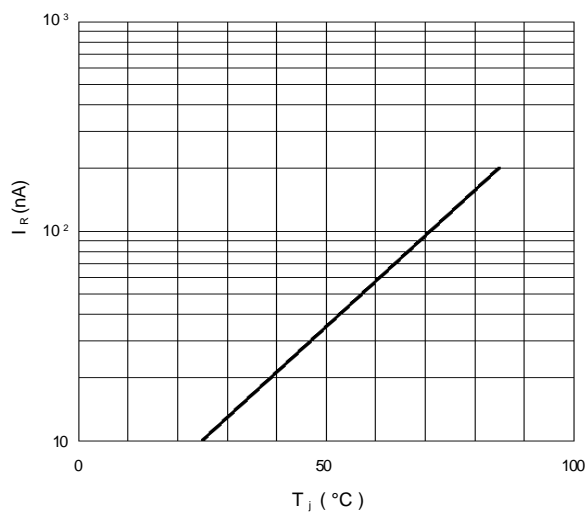


Fig.2 Reverse current as a function of junction temperature; maximum values.

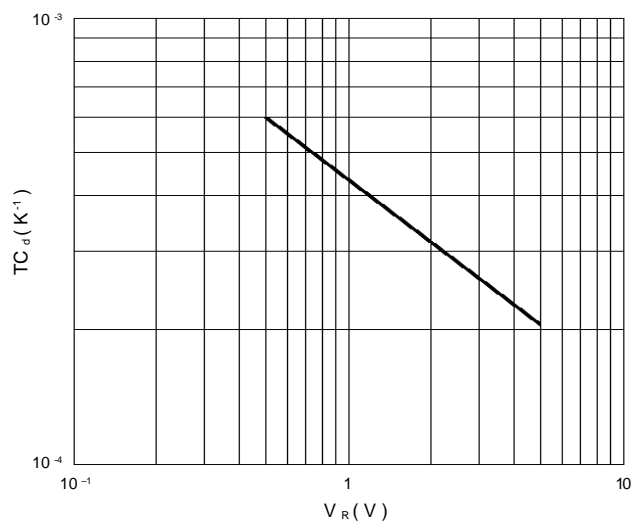


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.